

Power Management LSI Series for Automotive Body Control

LDO Regulator



BD3940FP, BD3941FP/HFP/T

●Description

BD394□FP Series regulators feature a high 36 V breakdown voltage and are compatible with onboard vehicle microcontrollers. They offer an output current of 500 mA while limiting dark current to 30 μ A (TYP). The series supports the use of ceramic capacitors as output phase compensation capacitors. Since the ICs use P-channel DMOS output transistors, increased loads do not result in increased total supply current. BD394□FP Series is ideal for lowering current consumption and costs in battery direct-coupled systems.

●Features

- 1) Super-low dark current: 30 μ A (Typ.)
- 2) Low-saturation voltage type P-channel DMOS output transistors
Output on resistance: 1.6 Ω (Typ.)
- 3) High precision output voltage: 5 V $\pm$ 2% ($T_a = 25^\circ\text{C}$) / $I_{\text{omax}} = 500$ mA
- 4) Low-ESR ceramic capacitors can be used as output capacitors
- 5) V_{cc} power supply voltage = 36 V / Peak power supply voltage = 50 V ($t_r \geq 1$ ms, $t_H \leq 200$ ms)
- 6) Built-in over current protection circuit and thermal shutdown circuit
- 7) TO252-3/HRP-5/TO220FP-3 package

●Applications

Vehicle equipment, car stereos, satellite navigation systems, etc.

●Product line

Model	BD3940FP	BD3941FP/HFP/T
Output voltage	3.3 V	5.0 V

●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limit	Unit
Power supply voltage	V_{cc}	36 ^{*1}	V
Output current	I_o	500	mA
Power dissipation	P_d	1.2 ^{*2}	W
		1.6 ^{*3}	
		2.0 ^{*4}	
Operating temperature range	T_{opr}	-40 to +125	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to +150	$^\circ\text{C}$
Peak power supply voltage	$V_{\text{cc Peak}}$	50 ^{*5}	V
Maximum junction temperature	T_{jmax}	150	$^\circ\text{C}$

* 1Not to exceed P_d .

*2 For TO252-3, reduced by 9.6 mW/ $^\circ\text{C}$ over 25°C , when mounted on a glass epoxy board (70 mm $\times$ 70 mm $\times$ 1.6 mm).

*3 Reduced by 12.8 mW/ $^\circ\text{C}$ over 25°C , when mounted on a glass epoxy board (70 mm $\times$ 70 mm $\times$ 1.6 mm).

*4 For TO220FP-3, reduced by 16.0 mW/ $^\circ\text{C}$ over 25°C .

*5 Application time 200 ms or shorter. ($t_r \geq 1$ ms)

●Recommended operating conditions (Ta = 25°C)

Parameter		Symbol	Min.	Max.	Unit
Input voltage	BD3940FP/HFP	V _{cc}	4.5	25.0	V
	BD3941FP/HFP/T	V _{cc}	6.2	25.0	V
Output current		I _o	—	500	mA

●Electrical characteristics (Unless otherwise specified, Ta = 25°C; V_{cc} = 13.2 V; I_o = 200 mA)

Parameter		Symbol	Limit			Unit	Conditions
			Min.	Typ.	Max.		
Bias current 1		I _{b1}	—	30	40	μA	I _o = 0 mA
Bias current 2		I _{b2}	—	30	—	μA	I _o = 200 mA
Output voltage	BD3940FP	V _o	3.234	3.300	3.366	V	
	BD3941FP/HFP/T	V _o	4.900	5.000	5.100	V	
Output current		I _o	500	—	—	mA	
Minimum I/O voltage difference	BD3940FP	ΔV _d	—	0.45	0.65	V	V _{cc} = 3.135 V, I _o = 100 mA
	BD3941FP/HFP/T						V _{cc} = 4.75 V, I _o = 200 mA
Ripple rejection		R.R.	45	55	—	dB	f = 120 Hz, e _{in} = 1 V _{rms} , I _o = 100 mA
Input stability	BD3940FP	Reg.I	—	10	30	mV	V _{cc} = 4.5 V → 25 V
	BD3941FP/HFP/T						V _{cc} = 6.2 V → 25 V
Load stability		Reg.L	—	20	60	mV	I _o = 0 mA → 200 mA

●Electrical characteristics (Unless otherwise specified, Ta = -40°C to +125°C; V_{cc} = 13.2 V; I_o = 200 mA)

Parameter		Symbol	Limit			Unit	Conditions
			Min.	Typ.	Max.		
Bias current 1		I _{b1}	—	30	40	μA	I _o = 0 mA
Bias current 2		I _{b2}	—	30	—	μA	I _o = 200 mA
Output voltage	BD3940FP	V _o	3.168	3.300	3.366	V	
	BD3941FP/HFP/T	V _o	4.800	5.000	5.100	V	
Output current		I _o	500	—	—	mA	
Minimum I/O voltage difference	BD3940FP	ΔV _d	—	—	0.9	V	V _{cc} = 3.135 V, I _o = 100 mA
	BD3941FP/HFP/T						V _{cc} = 4.75 V, I _o = 200 mA
Ripple rejection		R.R.	45	55	—	dB	f = 120 Hz, e _{in} = 1 V _{rms} , I _o = 100 mA
Input stability	BD3940FP	Reg. I	—	10	45	mV	V _{cc} = 4.5 V → 25 V
	BD3941FP/HFP/T						V _{cc} = 6.2 V → 25 V
Load stability		Reg.L	—	20	60	mV	I _o = 0 mA → 200 mA

Note: This IC is not designed to be radiation-resistant.

Note: All characteristics are measured with 0.33 μF and 0.1 μF capacitors connected to input and output pins, respectively.

Because measurements (pulse measurements) were taken when Ta ≈ Tj, data other than the output voltage/temperature coefficient does not include fluctuations due to temperature variations.

●Reference data (Unless otherwise specified, $T_a = 25^\circ\text{C}$)

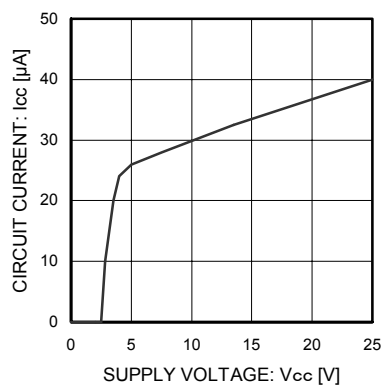


Fig. 1 Total Supply Current

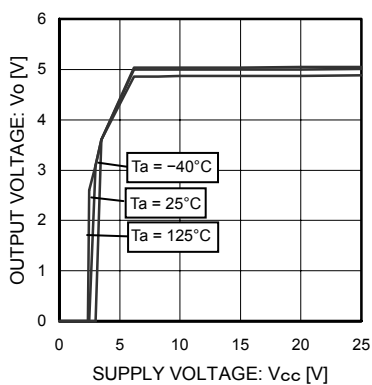


Fig. 2 Output Voltage vs Power Supply Voltage

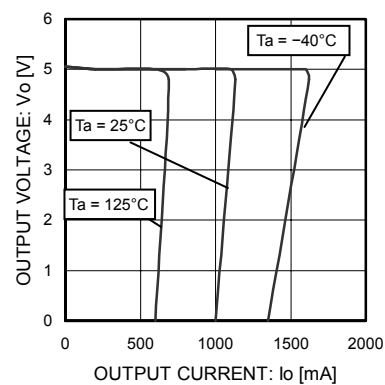


Fig. 3 Output Voltage vs Load

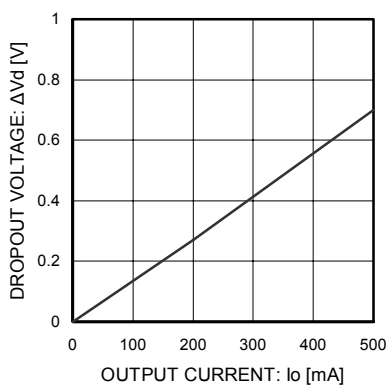


Fig. 4 I/O Voltage Difference

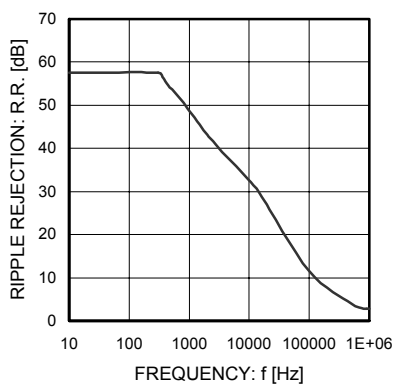


Fig. 5 Ripple Rejection

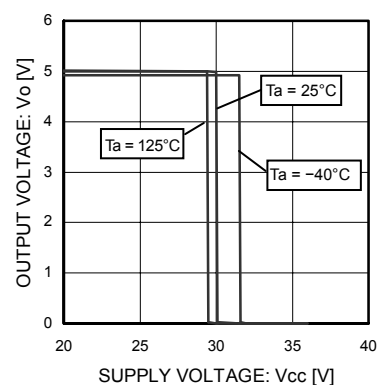


Fig. 6 Overvoltage Protection

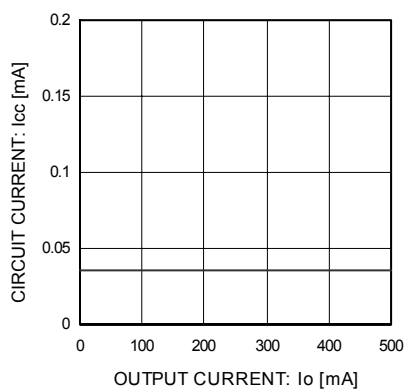


Fig. 7 Total Supply Current Classified by Load

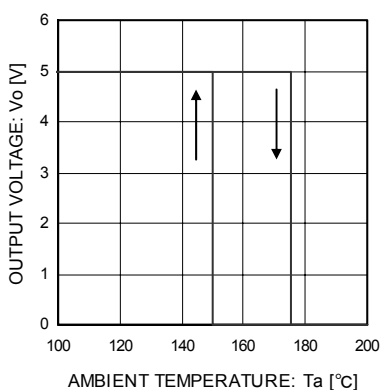


Fig. 8 Thermal Shutdown Circuit

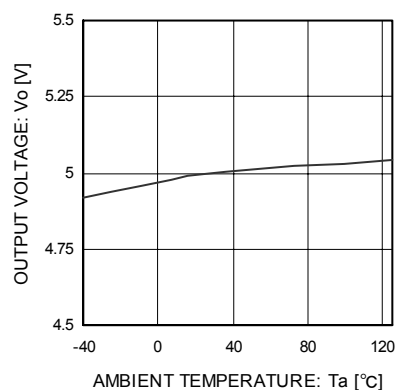


Fig. 9 Output Voltage vs Temperature

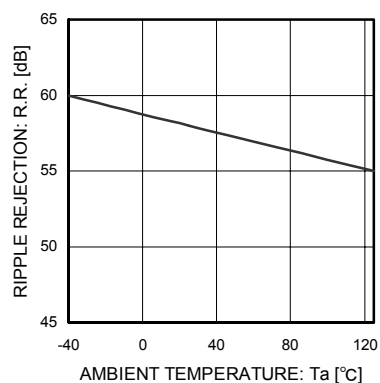


Fig. 10 Ripple Rejection vs Temperature

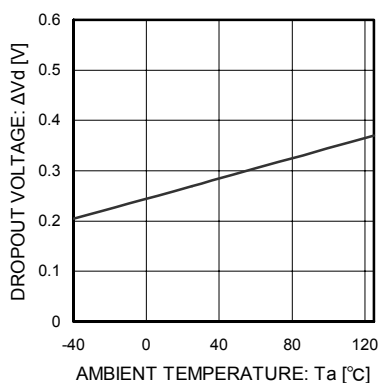


Fig. 11 Min. I/O Voltage Differential vs Temperature

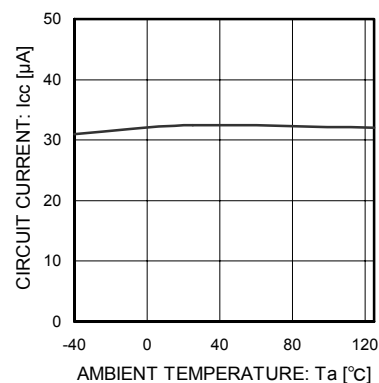


Fig. 12 Total Supply Current vs Temperature

●Block diagram

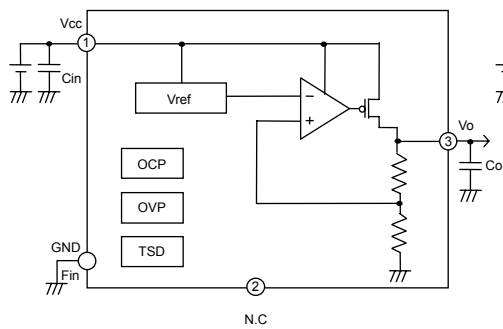


Fig.13 TO252-3

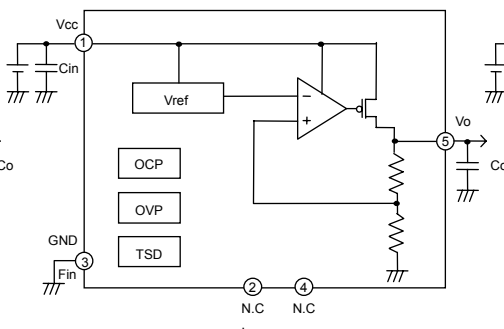


Fig.14 HRP5

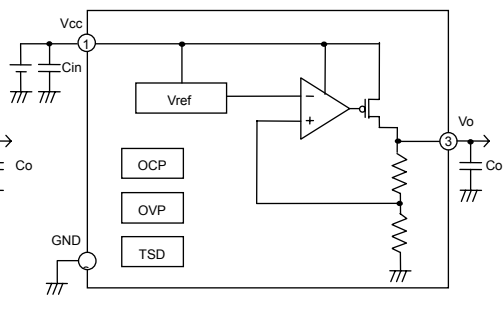


Fig.15 TO220FP-3

Cin : 0.33 μ F to 1000 μ F
Co : 0.1 μ F to 1000 μ F

●Pin assignments

• TO252-3

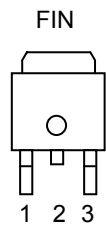


Fig.16

Pin No.	Pin No.	Function
1	Vcc	Power supply pin
2	N.C.	NC pin
3	Vo	Voltage output pin
Fin	GND	Ground pin

• HRP5

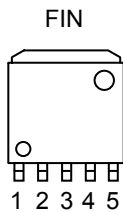


Fig.17

Pin No.	Pin No.	Function
1	Vcc	Power supply pin
2	N.C.	NC pin
3	GND	Ground pin
4	N.C.	NC pin
5	Vo	Voltage output pin
Fin	GND	Ground pin

• TO220FP-3

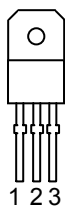


Fig.18

Pin No.	Pin No.	Function
1	Vcc	Power supply pin
2	GND	Ground pin
3	Vo	Voltage output pin

●Thermal design

TO252-3

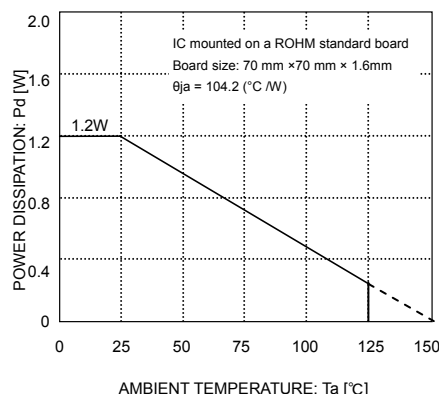


Fig.19

HRP5

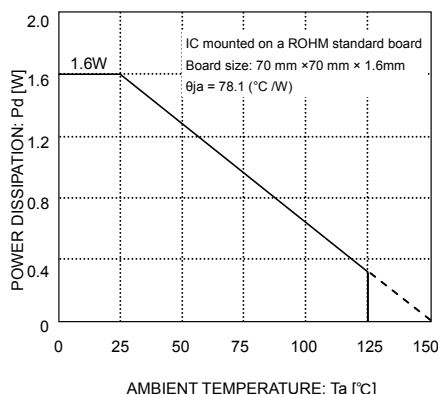


Fig.20

TO220FP-3

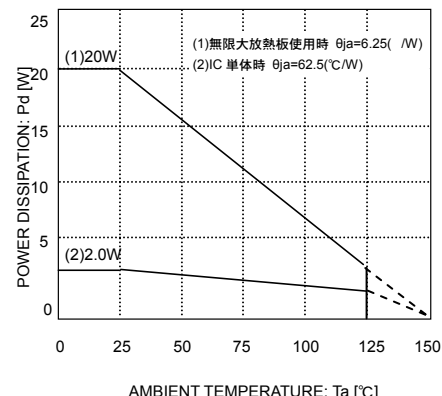


Fig.21

Refer to the dissipation reduction illustrated in Figs. 19 to 21 when using the IC in an environment where $T_a \geq 25^\circ\text{C}$. The characteristics of the IC are greatly influenced by the operating temperature. If the temperature exceeds the maximum junction temperature $T_{j\text{max}}$, the elements of the IC may be damaged. It is necessary to give sufficient consideration to the heat of the IC in view of two points, i.e., the protection of the IC from instantaneous damage and the maintenance of the reliability of the IC in long-time operation.

In order to protect the IC from thermal destruction, the operating temperature of the IC must not exceed the maximum junction temperature $T_{j\text{max}}$. Fig. 19 illustrates the power dissipation/power reduction for the TO252 package. Operate the IC within the power dissipation P_d . The following method is used to calculate the power consumption P_c (W).

$$P_c = (V_{cc} - V_o) \times I_o + V_{cc} \times I_{cc}$$

$$\text{Power dissipation } P_d \leq P_c$$

V_{cc} : Input voltage
 V_o : Output voltage
 I_o : Load current
 I_{cc} : Total supply current

The load current I_o is obtained to operate the IC within the power dissipation.

$$I_o \leq \frac{P_d - V_{cc} \times I_{cc}}{V_{cc} - V_o} \quad (\text{Refer to } I_{cc} \text{ in Fig.12})$$

The maximum load current $I_{o\text{max}}$ for the applied voltage V_{cc} can be calculated during the thermal design process.

Calculation example

Example) $V_{cc} = 12\text{ V}$ and $V_o = 5.0\text{ V}$ at $T_a = 85^\circ\text{C}$, BD3941FP

$$I_o \leq \frac{0.624 - 12 \times I_{cc}}{12 - 5}$$

$$I_o \leq 89\text{ mA} \quad (I_{cc} = 30\text{ }\mu\text{A})$$

$\theta_{ja} = 104.2^\circ\text{C/W} \rightarrow -9.6\text{ mAW}/^\circ\text{C}$
 $25^\circ\text{C} = 1.2\text{ W} \rightarrow 85^\circ\text{C} = 0.624\text{ W}$

Make a thermal calculation in consideration of the above equations so that the whole operating temperature range will be within the power dissipation. The power consumption P_c of the IC, in the event of shorting (i.e., if the V_o and GND pins are shorted), will be obtained from the following equation:

$$P_c = V_{cc} \times (I_{cc} + I_{\text{short}}) \quad I_{\text{short}}: \text{Short current}$$

●External settings for pins and precautions

1) V_{cc} pin

Insert capacitors with a capacitance of $0.33\text{ }\mu\text{F}$ to $1,000\text{ }\mu\text{F}$ between the V_{cc} and GND pins.

The capacitance varies with the application. Be sure to design the capacitance with a sufficient margin.

2) Capacitors for stopping oscillation at output pins

Capacitors for stopping oscillation must be placed between each output pin and the GND pin. Use a capacitor within a capacitance range between $1\text{ }\mu\text{F}$ and $1,000\text{ }\mu\text{F}$. A ceramic capacitor with low ESR values, from $0.001\text{ }\Omega$ to 100 , can be used. Unstable input voltage and load fluctuations can affect output voltages. Output capacitor capacitance values should be determined for actual application.

● Operation Notes

1) Absolute maximum ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.

2) GND voltage

The potential of GND pin must be minimum potential in all operating conditions.

3) Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (P_d) in actual operating conditions.

4) Inter-pin shorts and mounting errors

Use caution when positioning the IC for mounting on printed circuit boards. The IC may be damaged if there is any connection error or if pins are shorted together.

5) Actions in strong electromagnetic field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

6) Testing on application boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process. Ground the IC during assembly steps as an antistatic measure. Use similar precaution when transporting or storing the IC.

7) Regarding input pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated.

P-N junctions are formed at the intersection of these P layers with the N layers of other elements, creating a parasitic diode or transistor.

For example, the relation between each potential is as follows:

When $GND > Pin\ A$ and $GND > Pin\ B$, the P-N junction operates as a parasitic diode.

When $GND > Pin\ B$, the P-N junction operates as a parasitic transistor.

Parasitic diodes can occur inevitable in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Accordingly, methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin, should not be used.

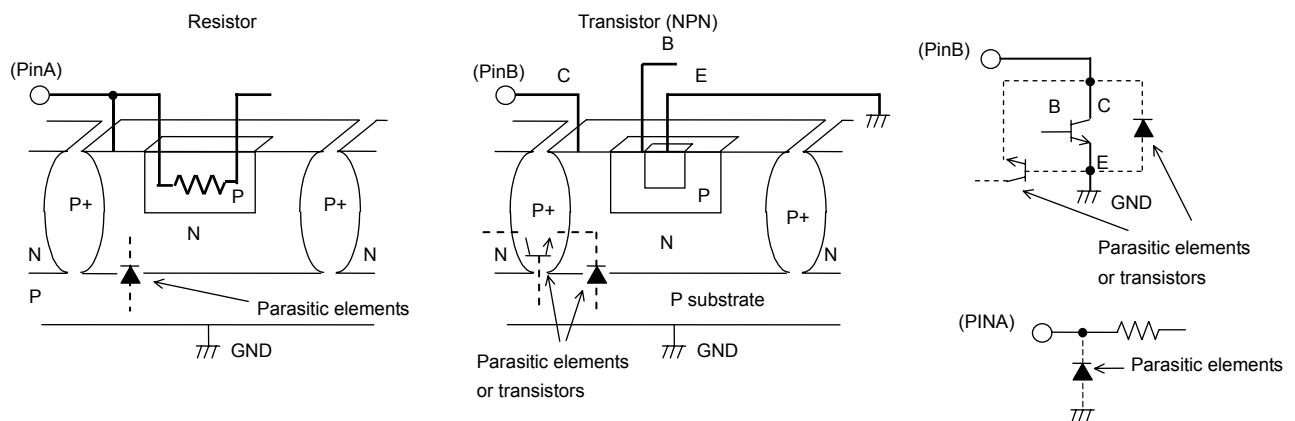


Fig.22 Example of a Simple Monolithic IC Architecture

8) Ground Wiring Pattern

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the ground potential of application so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring pattern of any external components, either.

- 9) Applications or inspection processes with modes where the potentials of the Vcc pin and other pins may be reversed from their normal states may cause damage to the IC's internal circuitry or elements.
 Use an output pin capacitance of 1,000 μ F or lower in case Vcc is shorted with the GND pin while the external capacitor is charged. It is recommended to insert a diode for preventing back current flow in series with Vcc or bypass diodes between Vcc and each pin.

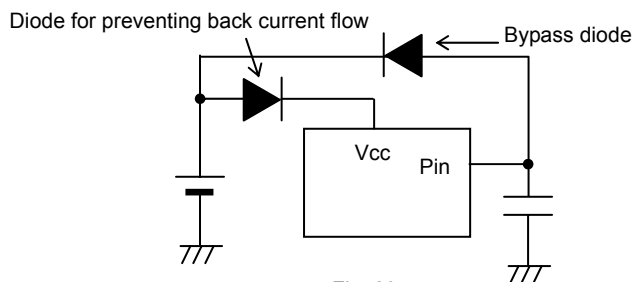


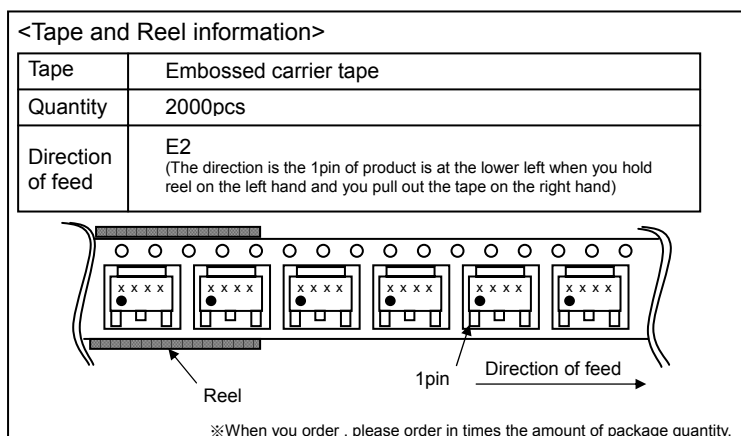
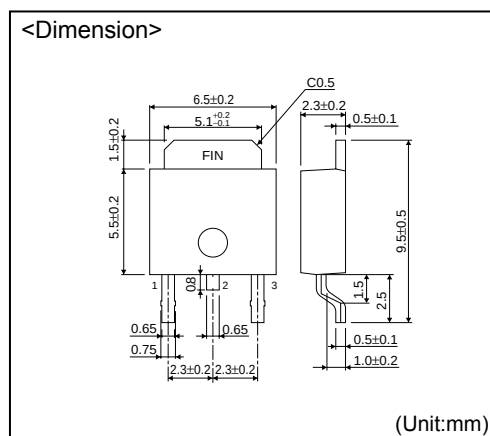
Fig. 23

- 10) Thermal shutdown circuit (TSD)
 This IC incorporates a built-in thermal shutdown circuit for the protection from thermal destruction. The IC should be used within the specified power dissipation range. However, in the event that the IC continues to be operated in excess of its power dissipation limits, the attendant rise in the chip's temperature T_j will trigger the thermal shutdown circuit to turn off all output power elements. The circuit will automatically reset once the chip's temperature T_j drops. Operation of the thermal shutdown circuit presumes that the IC's absolute maximum ratings have been exceeded. Application designs should never make use of the thermal shutdown circuit. (See Fig. 8)
- 11) Overcurrent protection circuit (OCP)
 The IC incorporates a built-in overcurrent protection circuit that operates according to the output current capacity. This circuit serves to protect the IC from damage when the load is shorted. The protection circuit is designed to limit current flow by not latching in the event of a large and instantaneous current flow originating from a large capacitor or other component. However, while this protection circuit is effective in preventing damage due to sudden and unexpected accidents, it is not compatible with continuous operation or use during transitional periods. At the time of thermal designing, keep in mind that the current capability has negative characteristics to temperatures. (See Fig. 3.)
- 12) Overvoltage protection circuit (OVP)
 Overvoltage protection is designed to turn off all output when the voltage differential between the VCC and GND pins exceeds approximately 30 V (typ.). Use caution when determining the power supply voltage range to use. (See Fig. 6)

●Selecting a model name when ordering

B	D	3	9	4	1	F	P		—	E	2
ROHM model name		Part number				Packaging type			Taping		
		3940: 3.3 V output				FP : TO252-3			E2 : Reel-wound embossed taping		
		3941: 5.0 V output				HFP : HRP5					
						T : TO220FP-3					

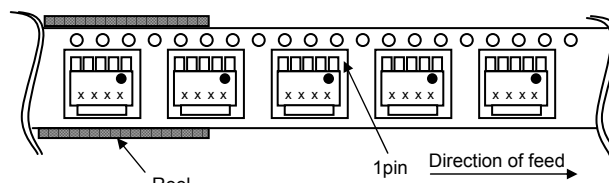
TO252-3



9.395 ± 0.125
(MAX 9.745 include BURR)
8.82 ± 0.1
(5.59)
10.17 ± 0.2
8.0 ± 0.13
1.2575
1
2
3
4
5
(7.64)
1.905 ± 0.1
0.855 ± 0.2
1.523 ± 0.12
10.94 ± 0.13
4.5° ± 0.5°
0.27 ± 0.05
0.08 ± 0.05
1.72
0.73 ± 0.1
EN 10001-2

(Unit:mm)

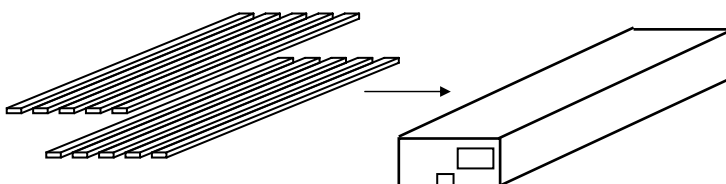
Tape	Embossed carrier tape
Quantity	2000pcs
Direction of feed	TR (The direction is the 1pin of product is at the upper light when you hold reel on the left hand and you pull out the tape on the right hand)



※When you order , please order in times the amount of package quantity.

<Dimension>

Container	Tube
Quantity	500pcs
Direction of feed	Direction of products is fixed in a container tube.



※When you order , please order in times the amount of package quantity.

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- The contents described herein are subject to change without notice. For updates of the latest information, please contact and confirm with ROHM CO.,LTD.
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- The products described herein utilize silicon as the main material.
- The products described herein are not designed to be X ray proof.

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